

# RT1P434X SERIES

Transistor

Transistor With Resistor  
For Switching Application  
Silicon PNP Epitaxial Type

## DESCRIPTION

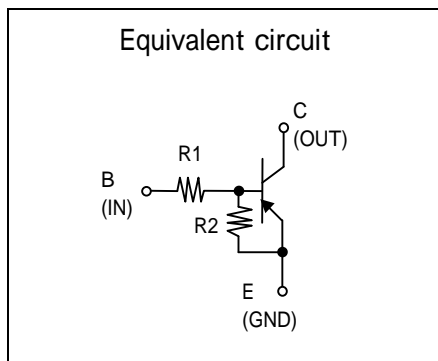
RT1P434X is a one chip transistor with built-in bias resistor, NPN type is RT1N434X.

## FEATURE

- Built-in bias resistor (R1=4.7k, R2=22k).

## APPLICATION

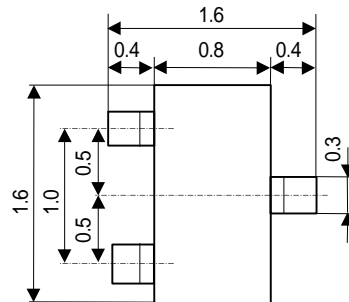
Inverted circuit, switching circuit, interface circuit, driver circuit.



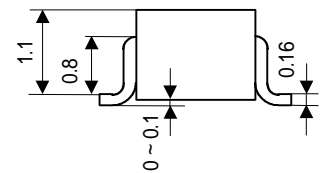
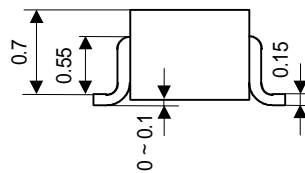
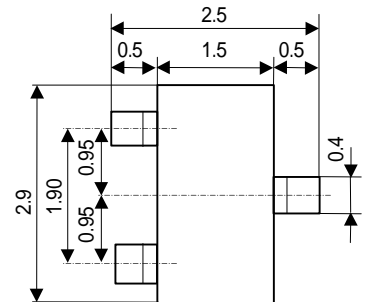
## OUTLINE DRAWING

UNIT : mm

RT1P434U



RT1P434C



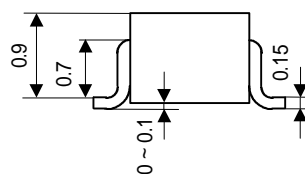
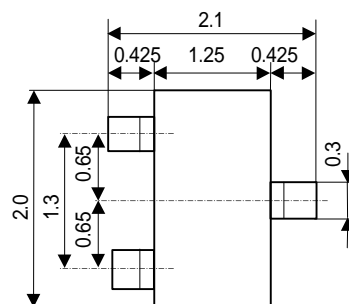
JEITA: -  
JEDEC: -

Terminal Connector  
: Base  
: Emitter  
: Collector

JEITA: SC-59  
JEDEC: Similar to TO-236

Terminal Connector  
: Base  
: Emitter  
: Collector

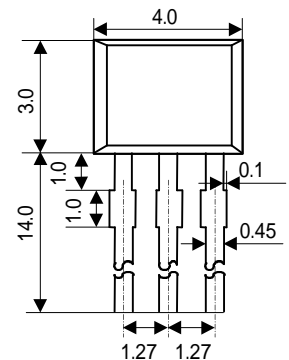
RT1P434M



JEITA: SC-70  
JEDEC: -

Terminal Connector  
: Base  
: Emitter  
: Collector

RT1P434S



JEITA: -  
JEDEC: -

Terminal Connector  
: Emitter  
: Collector  
: Base

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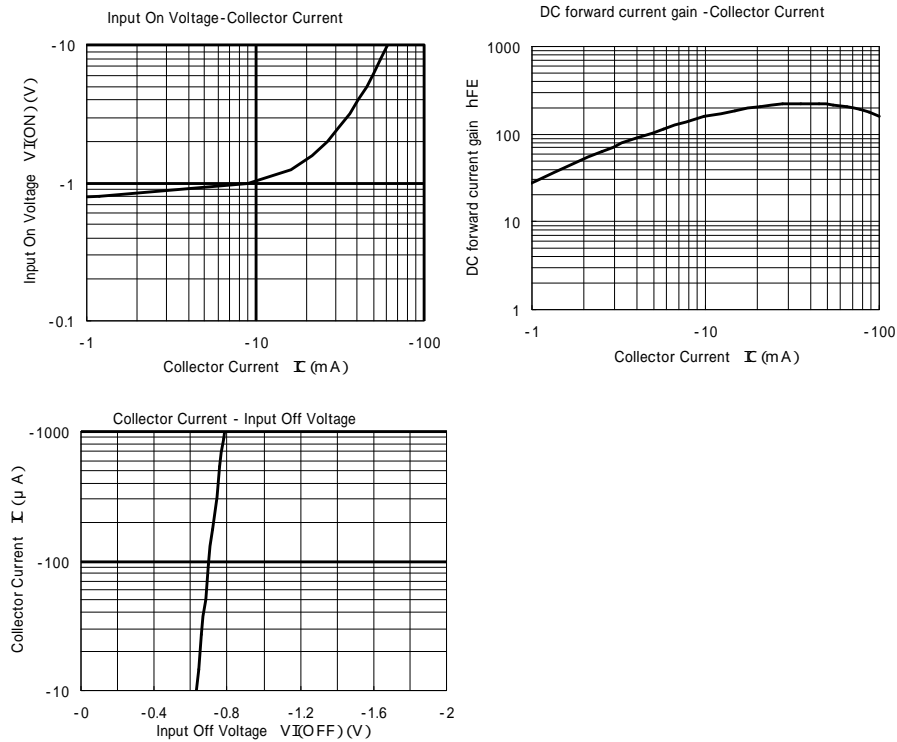
## MAXIMUM RATING (Ta=25 )

SYMBOL	PARAMETER	RATING				UNIT
		RT1P434U	RT1P434M	RT1P434C	RT1P434S	
$V_{CBO}$	Collector to Base voltage	-50				V
$V_{EBO}$	Emitter to Base voltage	-6				V
$V_{CEO}$	Collector to Emitter voltage	-50				V
$I_C$	Collector current	-100				mA
$I_{CM}$	Peak Collector current	-200				mA
$P_C$	Collector dissipation(Ta=25 )	150	200	450	mW	
$T_j$	Junction temperature	+150	+150			
$T_{stg}$	Storage temperature	-55 ~ +150		-55 ~ +150		

## ELECTRICAL CHARACTERISTICS (Ta=25 )

SYMBOL	PARAMETER	TEST CONDITION	LIMIT			UNIT
			MIN	TYP	MAX	
$V_{(BR)CEO}$	C to E break down voltage	$I_C = -100 \mu A, R_{BE} =$	-50			V
$I_{CBO}$	Collector cut off current	$V_{CB} = -50V, I_E = 0$			-0.1	$\mu A$
$h_{FE}$	DC forward current gain	$V_{CE} = -5V, I_C = -5mA$	50			-
$V_{CE(sat)}$	C to E saturation voltage	$I_C = -10mA, I_B = -0.5mA$		-0.1	-0.3	V
$V_{I(ON)}$	Input on voltage	$V_{CE} = -0.2V, I_C = -5mA$		-0.9	-1.7	V
$V_{I(OFF)}$	Input off voltage	$V_{CE} = -5V, I_C = -100 \mu A$	-0.5	-0.7		V
$R_1$	Input resistance		3.3	4.7	6.1	k
$R_2 / R_1$	Resistance ratio		4.2	4.7	5.1	
$f_T$	Gain band width product	$V_{CE} = -6V, I_E = 10mA$		150		MHz

## TYPICAL CHARACTERISTICS





*Marketing division, Marketing planning department*

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